

VS-45L(R), VS-150K(R), VS-150KS(R) Series

Vishay Semiconductors

Standard Recovery Diodes (Stud Version), 150 A



PRODUCT SUMMARY				
I _{F(AV)}	150 A			
Package	DO-205AA (DO-8)			
Circuit configuration	Single diode			

FEATURES

- Alloy diode
- High current carrying capability
- High surge current capabilities
- Stud cathode and stud anode version
- Designed and qualified for industrial level
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- Battery chargers
- Welders
- Machine tool controls
- High power drives
- Medium traction applications
- Freewheeling diodes

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
. I		150	А		
l _{F(AV)}	T _C	150	°C		
I _{F(RMS)}		235	А		
	50 Hz	3570	0		
IFSM	60 Hz	3740	A		
l ² t	50 Hz	64	kA ² s		
	60 Hz	58	KA-S		
V _{RRM}	Range	100 to 600	V		
TJ		-40 to 200	°C		

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS					
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = 175 °C mA	
	10	100	200		
VS-45L(R)	20	200	300		
VS-150K(R)	30	300	400	35	
VS-150KS(R)	40	400	500		
	60	600	720		

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PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current		180° conduction, half sine wave		150	А	
at case temperature	I _{F(AV)}			ve	150	°C
Maximum RMS forward current	I _{F(RMS)}	DC at 142 °C case temperature		re	235	
		t = 10 ms	No voltage	Sinusoidal half wave, initial TJ = TJ maximum	3570	A
Maximum peak, one cycle forward,		t = 8.3 ms	reapplied		3740	
non-repetitive surge current	I _{FSM}	t = 10 ms	100 % V _{RRM}		3000	
		t = 8.3 ms	reapplied		3140	
Maximum I ² t for fusing	l ² t	t = 10 ms	No voltage		64	- kA ² s
		t = 8.3 ms	reapplied		58	
		t = 10 ms	100 % V _{RRM} reapplied		45	
		t = 8.3 ms			41	
Maximum I ² \sqrt{t} for fusing	l²√t	t = 0.1 to 10 ms, no voltage reapplied		640	kA²√s	
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % x π x $I_{F(AV)} < I < \pi$ x $I_{F(AV)}$), $T_J = T_J$ maximum		0.67	v	
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi \times I_{F(AV)}), T_J = T_J maximum$		0.83	v	
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum		1.42	mW	
High level value of forward slope resistance	r _{f2}	$(I > \pi \times I_{F(AV)}), T_J = T_J maximum$		0.91	IIIVV	
Maximum forward voltage drop	V _{FM}	$I_{pk} = 471 \text{ A}, T_J = 25 \text{ °C}, t_p = 10 \text{ ms}$ sinusoidal wave		1.33	V	

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
	Maximum junction operating and storage temperature range			-40 to 200	°C
Maximum thermal resist junction to case	ance,	R _{thJC}	DC operation	0.25	K/W
Maximum thermal resist case to heatsink	ance,	R _{thCS}	Mounting surface, smooth, flat and greased	0.10	
	minimum		Not lubricated threads	14.1 (125)	N · m (lbf · in)
Mounting torque	maximum		Not lubricated threads	17.0 (150)	
45L	minimum		Lubricated threads	12.2 (108)	
	maximum		Lubricated threads	15.0 (132)	
	minimum		Not lubricated threads	11.3 (100)	N · m (lbf · in)
Mounting torque	maximum		Not lubricated threads	14.1 (125)	
150K 150KS	minimum			9.5 (85)	
	maximum		Lubricated threads	12.5 (110)	1
Approximate weight				100	g
				3.5	oz.
	45L		DO-205AC (DO-		(DO-30)
Case style	150K-A		See dimensions - link at the end of datasheet DO-205AA (DO-8		(DO-8)
	150KS	1		B-42	

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CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS	
180°	0.031	0.023			
120°	0.038	0.040			
90°	0.048	0.053	$T_J = T_J$ maximum	K/W	
60°	0.071	0.075			
30°	0.120	0.121			

Note

The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

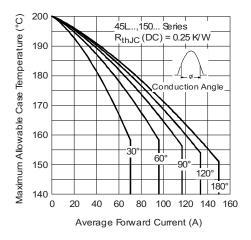


Fig. 1 - Current Ratings Characteristics

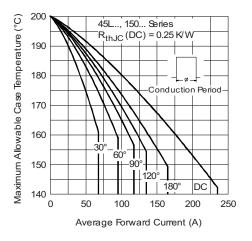


Fig. 2 - Current Ratings Characteristics

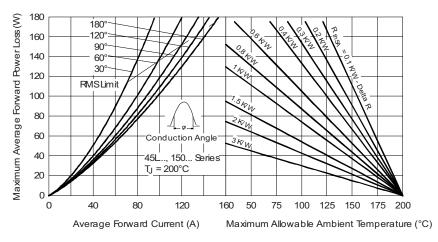
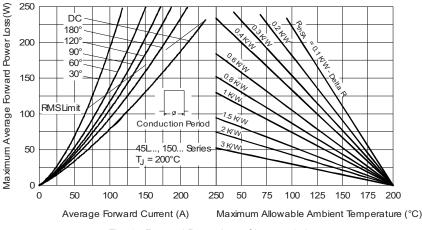


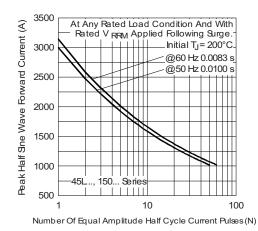
Fig. 3 - Forward Power Loss Characteristics

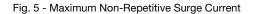


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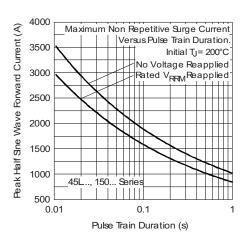


Fig. 6 - Maximum Non-Repetitive Surge Current

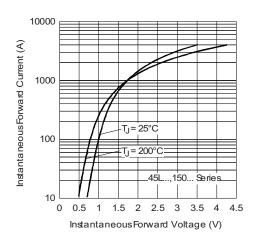
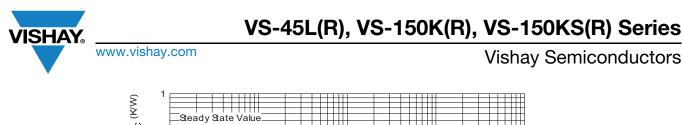


Fig. 7 - Forward Voltage Drop Characteristics

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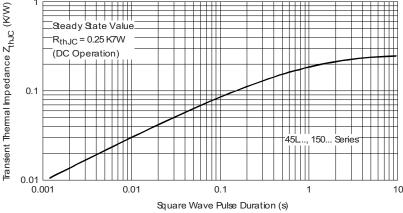
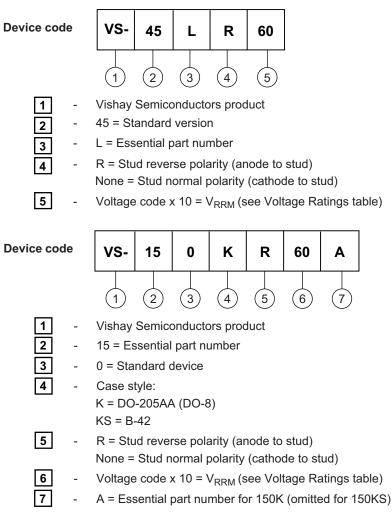


Fig. 8 - Thermal Impedance ZthJC Characteristics

ORDERING INFORMATION TABLES



Note: For metric device M12 x 1.75 contact factory

LINKS TO RELATED DOCUMENTS				
Dimensions	WWW	.vishay.com/doc?95314		
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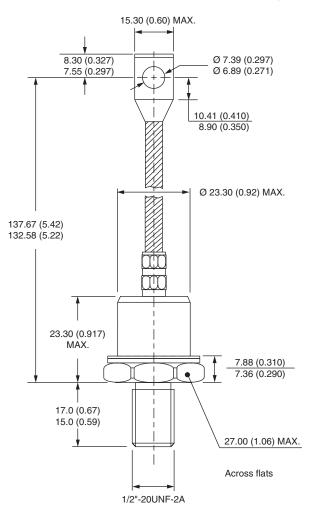
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DO-205AC (DO-30), DO-205AA (DO-8) and B-42 for 45L(R), 150K(R) and 150KS(R) Series

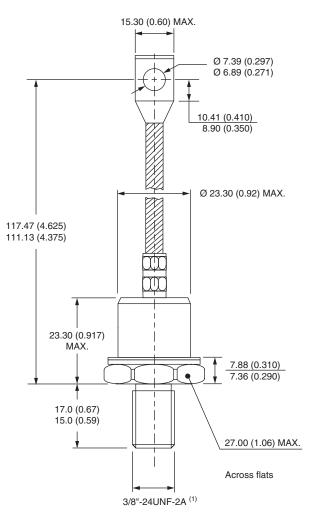
DIMENSIONS FOR 45L(R) SERIES - DO-205AC (DO-30) in millimeters (inches)





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DIMENSIONS FOR 150K(R) SERIES - DO-205AA (DO-8) in millimeters (inches)



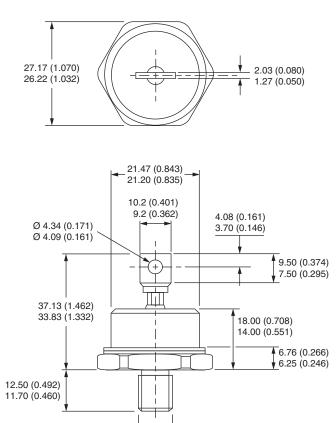
Note

⁽¹⁾ For metric device M12 x 1.75 contact factory





DIMENSIONS FOR 150KS(R) SERIES - B-42 in millimeters (inches)



3/8"-24UNF-2A

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